Single Channel, DC Sensing Input, Phototransistor Optocoupler In Stretched Body SOP 4-Pin



Description

The FODM100x Series, single channel, DC sensing input, optocoupler consists of one gallium arsenide (GaAs) infrared light emitting diode optically coupled to one phototransistor, in a stretched body SOP 4–pin package. The input–output isolation voltage, V_{ISO} , is rated at 5,000 VAC_{RMS}.

Features

- ≥ 8 mm Creepage and Clearance Distance, and ≥ 0.4 mm Insulation Distance to Achieve Reliable and High Voltage Insulation
- Safety and Regulatory Approvals
- UL1577, 5,000 VAC_{RMS} for 1 min
- DIN EN/IEC60747-5-5, 890 V Peak Working Voltage
- High Breakdown Collector to Emitter Voltage, BV_{CEO} = 70 V Minimum
- Extended Industrial Temperate Range, -40 to 110°C
- Current Transfer Ratio at $I_F = 5 \text{ mA}$, $V_{CE} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- FODM1007: 80 to 160%
- FODM1008: 130 to 260%
- FODM1009: 200 to 400%
- These are Pb–Free Devices

Applications

- Primarily Suited for DC-DC Converters
- For Ground Loop Isolation, Signal to Noise Isolation
- Communications Adapters, Chargers
- Consumer Appliances, Set-Top Boxes
- Industrial Power Supplies, Motor Control, Programmable Logic Control

Related Resources

- https://www.onsemi.com/products/optoelectronics/
- www.onsemi.com/datsheets/HM/HMHA2801.pdf



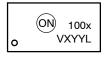
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SSOP4 / LSOP04 CASE 565BH

MARKING DIAGRAM

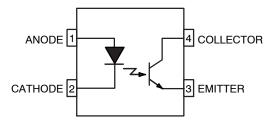


- 100x = Specific Device Code (x = 7, 8, 9) $V_{\text{DIN}} = \text{DIN} \text{EN}/\text{IEC60747} = 5 - 5 \text{Option}$ (on
 - = DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
- X = Last Digit Year Code
- YY = Two Digit Work Week

L

= Assembly Package Code

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

SAFETY AND INSULATION RATINGS (As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

| Parameter | | Characteristics |
|--|-----------------------|-----------------|
| Installation Classifications per DIN VDE | <150 V _{RMS} | I–IV |
| 0110/1.89 Table 1, For Rated Mains Voltage | <300 V _{RMS} | - |
| Climatic Classification | 40/110/21 | |
| Pollution Degree (DIN VDE 0110/1.89) | 2 | |
| Comparative Tracking Index | | 175 |

| Symbol | Parameter | Value | Unit |
|----------------------|---|------------------|-------------------|
| V _{PR} | Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10 \text{ s}$, Partial Discharge < 5 pC | 1,426 | V _{peak} |
| | Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1 \text{ s}$, Partial Discharge < 5 pC | 1,671 | V _{peak} |
| V _{IORM} | Maximum Working Insulation Voltage | 890 | V _{peak} |
| V _{IOTM} | Highest Allowable Over-Voltage | 6.000 | V _{peak} |
| | External Creepage | ≥8.0 | mm |
| | External Clearance | ≥8.0 | mm |
| DTI | Distance Through Insulation (Insulation Thickness) | ≥0.4 | mm |
| Τ _S | Case Temperature (Note 1) | 150 | °C |
| I _{S,INPUT} | Input Current (Note 1) | 200 | mA |
| S,OUTPUT | Output Power (Note 1) | 300 | mW |
| R _{IO} | Insulation Resistance at T _S , V _{IO} = 500 V (Note 1) | >10 ⁹ | Ω |

1. Safety limit values - maximum values allowed in the event of a failure.

 PD_C

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$, unless otherwise noted)

Detector Power Dissipation @ T_A = 25°C (Note 2)

Derate Above 25°C

| Symbol | Parameter | Value | Unit |
|---------------------|--|-------------|-------|
| TOTAL PA | CKAGE | | - |
| T _{STG} | Storage Temperature | –55 to +150 | °C |
| T _{OPR} | Operating Temperature | -40 to +110 | °C |
| Τ _J | Junction Temperature | -40 to +125 | °C |
| EMITTER | | | |
| I _{F(avg)} | Continuous Forward Current | 50 | mA |
| I _{F(pk)} | Continuous Forward Current (1 µs Pulse, 300 pps) | 1 | A |
| VR | Reverse Input Voltage | 6 | V |
| PD _{LED} | LED Power Dissipation @ $T_A = 25^{\circ}C$ (Note 2) | 100 | mW |
| | Derate Above 25°C | 0.9 | mW/°C |
| DETECTO | 3 | | |
| Ι _C | Continuous Collector Current | 50 | mA |
| V _{CEO} | Collector-Emitter Voltage | 70 | V |
| V_{ECO} | Emitter-Collector Voltage | 7 | V |
| | | | 1 |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

150

1.47

mW

mW/°C

2. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.

ELECTRICAL CHARACTERISTICS

 $T_A = 25^{\circ}C$ unless otherwise specified.

INDIVIDUAL COMPONENT CHARACTERISTICS

| Symbol | Parameter | Device | Test Conditions | Min | Тур | Max | Unit |
|-------------------|---|--------|---|-----|-----|-----|------|
| EMITTER | | | | | - | | |
| V _F | Forward Voltage | All | I _F = 50 mA | - | 1.4 | 1.6 | V |
| I _R | Reverse Current | All | V _R = 4 V | - | - | 10 | μA |
| DETECTOR | | | | | | | |
| BV _{CEO} | Breakdown Voltage Collector to Emitter | All | $I_{C} = 1 \text{ mA}, I_{F} = 0$ | 70 | _ | - | V |
| BV_{ECO} | Emitter to Collector | All | I _E = 0.1 mA, I _F = 0 | 7 | - | - | V |
| I _{CEO} | Collector Dark Current | All | V _{CE} = 70 V, I _F = 0 | - | - | 100 | nA |
| C _{CE} | Capacitance | All | V _{CE} = 0 V, f = 1 MHz | - | 5 | - | pF |

DC TRANSFER CHARACTERISTICS

| Symbol | Parameter | Device | Test Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------|----------|---|-----|-----|-----|------|
| CTR | DC Current Transfer Ratio | FODM1007 | I _F = 5 mA, V _{CE} = 5 V | 80 | - | 160 | % |
| | | FODM1008 | | 130 | _ | 260 | |
| | | FODM1009 | | 200 | _ | 400 | |
| V _{CE(SAT)} | Saturation Voltage | All | I _F = 10 mA, I _C = 1 mA | - | - | 0.3 | V |

AC TRANSFER CHARACTERISTICS

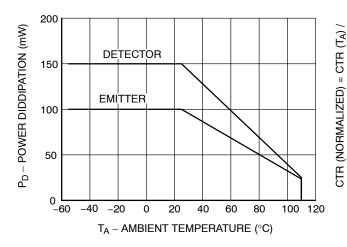
| Symbol | Parameter | Device | Test Conditions | Min | Тур | Мах | Unit |
|----------------|------------------------------|--------|--|-----|-----|------|------|
| t _r | Rise Time (Non-Saturated) | All | I_{C} = 2 mA, V_{CE} = 5 V, R_{L} = 100 Ω | - | 5.7 | 18.0 | μs |
| t _f | Fall Time (Non-Saturated) | All | I_{C} = 2 mA, V_{CE} = 5 V, R_{L} = 100 Ω | - | 8.5 | 18.0 | |

ISOLATION CHARACTERISTICS

| Symbol | Parameter | Device | Test Conditions | Min | Тур | Max | Unit |
|------------------|-----------------------------------|--------|--|-------|-----|-----|--------------------|
| V _{ISO} | Steady State Isolation Voltage | All | T_A = 25°C, R.H. < 50%, t =1.0 min., I_{I-O} \leq 20 μA | 5,000 | - | - | VAC _{RMS} |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CHARACTERISTICS



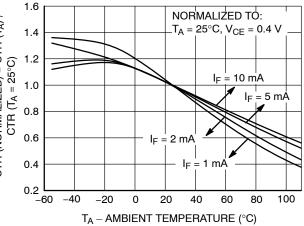


Figure 1. Power Dissipation vs. Ambient Temperature

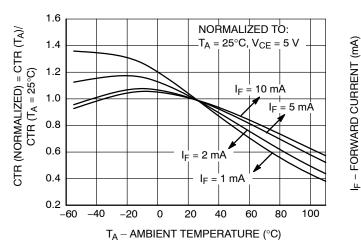


Figure 3. Non–Saturated Normalized Current Transfer Ratio vs. Ambient temperature

 $_{C}$ (NORMALIZED) = I_{C} (IF) / I_{C} (IF = 5 mA)

100

10

1

0.1

0.01

0.001

0.1

NORMALIZED TO:

25°C

I_F = 5 mA, V_{CE} = 5 V

Figure 2. Saturated Normalized Current Transfer Ratio vs. Ambient temperature

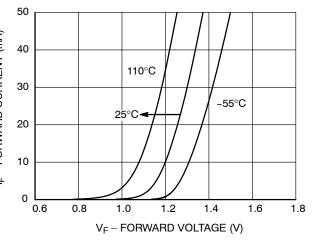


Figure 4. Forward Current vs. Forward Voltage

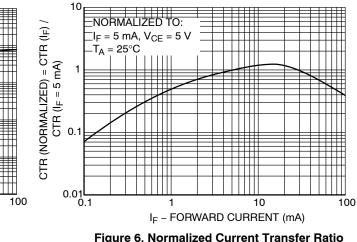
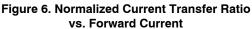


Figure 5. Normalized Current Collector vs. Forward Current

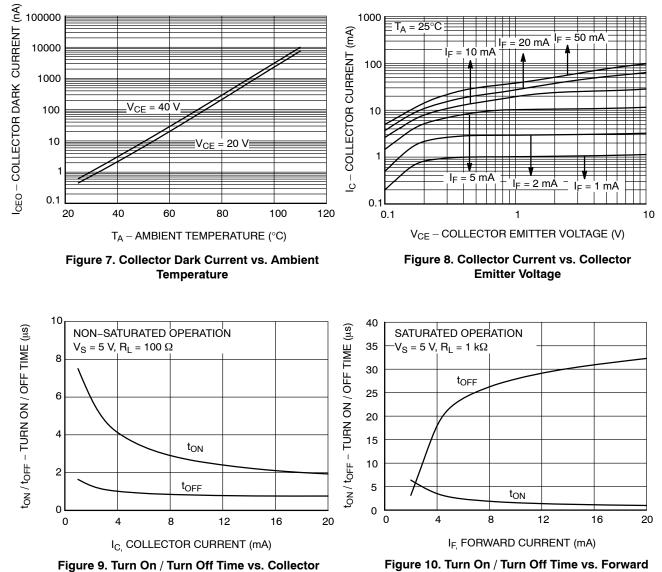
IF - FORWARD CURRENT (mA)

1

10



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



Current

Current

REFLOW PROFILE

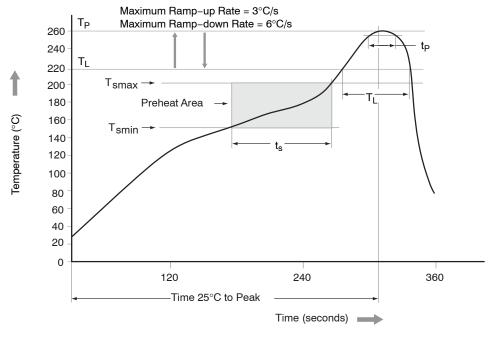




Table 1. REFLOW PROFILE

| Profile Freature | Pb-Free Assembly Profile |
|---|--------------------------|
| Temperature Minimum (T _{smin}) | 150°C |
| Temperature Maximum (T _{smax}) | 200°C |
| Time (t _S) from (T _{smin} to T _{smax}) | 60 – 120 seconds |
| Ramp–up Rate (t _L to t _P) | 3°C/second maximum |
| Liquidous Temperature (T _L) | 217°C |
| Time (t _L) Maintained Above (T _L) | 60 – 150 seconds |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (t _P) within 5°C of 260°C | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second maximum |
| Time 25°C to Peak Temperature | 8 minutes maximum |

ORDERING INFORMATION

| Part Number | Package | Shipping [†] |
|-------------|---|-----------------------|
| FODM1007 | Stretched Body SOP 4-Pin | 100 Units / Tube |
| FODM1007R2 | Stretched Body SOP 4-Pin | 3000 / Tape & Reel |
| FODM1007V | Stretched Body SOP 4–Pin, DIN EN/IEC60747–5–5 Option | 100 Units / Tube |
| FODM1007R2V | Stretched Body SOP 4–Pin, DIN EN/IEC60747–5–5 Option | 3000 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

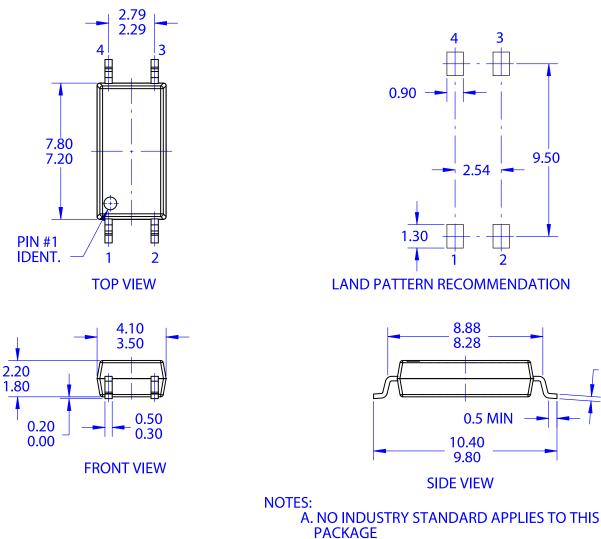
NOTE: The product orderable part number system listed in this table also applies to the FODM1008, FODM1009 products.



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B. ALL DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS

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